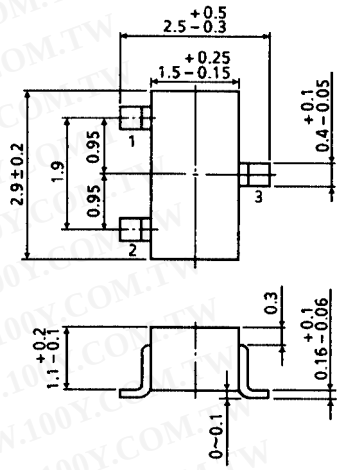
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC3324

Audio Frequency Low Noise Amplifier Applications

- High voltage: V_{CEO} = 120 V
- Excellent h_{FE} linearity: h_{FE} (I_C = 0.1 mA)/ h_{FE} (I_C = 2 mA) = 0.95 (typ.)
- High h_{FE}: h_{FE} = 200~700
- Low noise: NF (2) = 0.2dB (typ.), 3dB (max)
- Complementary to 2SA1312
- Small package

Unit: mm



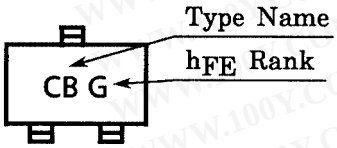
JEDEC	TO-236MOD
JEITA	SC-59
TOSHIBA	2-3F1A

Weight: 0.012 g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	120	V
Collector-emitter voltage	V_{CEO}	120	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_C	100	mA
Base current	I_B	20	mA
Collector power dissipation	P_C	150	mW
Junction temperature	T_j	125	°C
Storage temperature range	T_{stg}	−55~125	°C

Marking



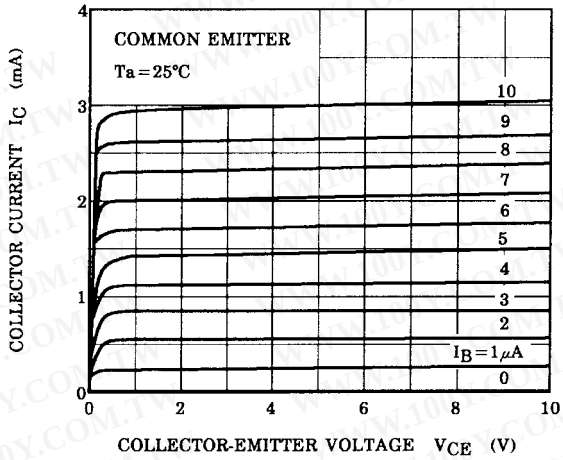
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	V_{CB} = 120 V, I_E = 0	—	—	0.1	μA
Emitter cut-off current	I_{EBO}	V_{EB} = 5 V, I_C = 0	—	—	0.1	μA
DC current gain	h_{FE} (Note)	V_{CE} = 6 V, I_C = 2 mA	200	—	700	
Collector-emitter saturation voltage	$V_{CE\ (sat)}$	I_C = 10 mA, I_B = 1 mA	—	—	0.3	V
Transition frequency	f_T	V_{CE} = 6 V, I_C = 1 mA	—	100	—	MHz
Collector output capacitance	C_{ob}	V_{CB} = 10 V, I_E = 0, f = 1 MHz	—	4	—	pF
Noise figure	NF (1)	V_{CB} = 6 V, I_C = 0.1 mA, f = 100 Hz, Rg = 10 kΩ	—	0.5	6	dB
	NF (2)	V_{CB} = 6 V, I_C = 0.1 mA, f = 1 kHz, Rg = 10 kΩ	—	0.2	3	

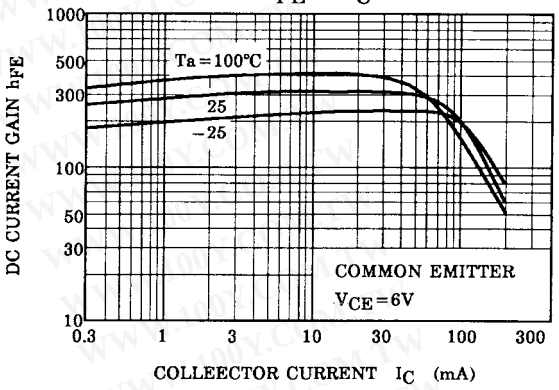
Note: h_{FE} classification GR (G): 200~400, BL (L): 350~700

( ) marking symbol

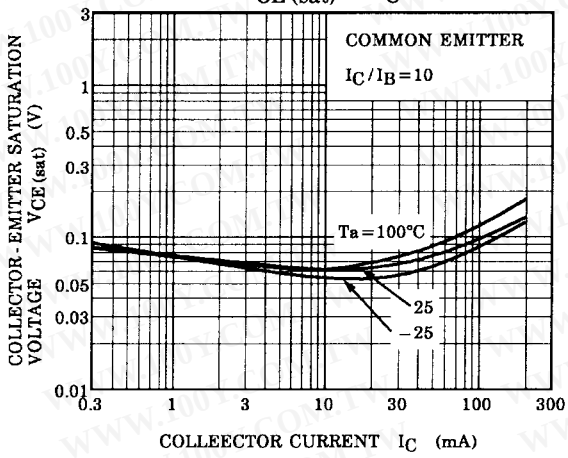
I_C – V_{CE}



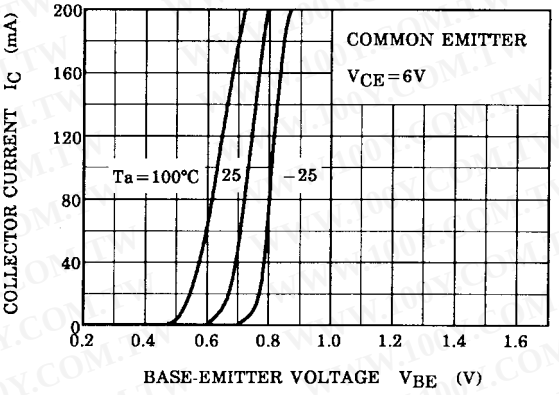
h_{FE} – I_C



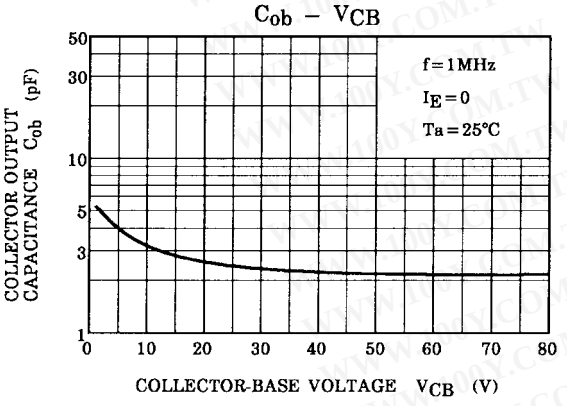
$V_{CE\,(sat)}$ – I_C



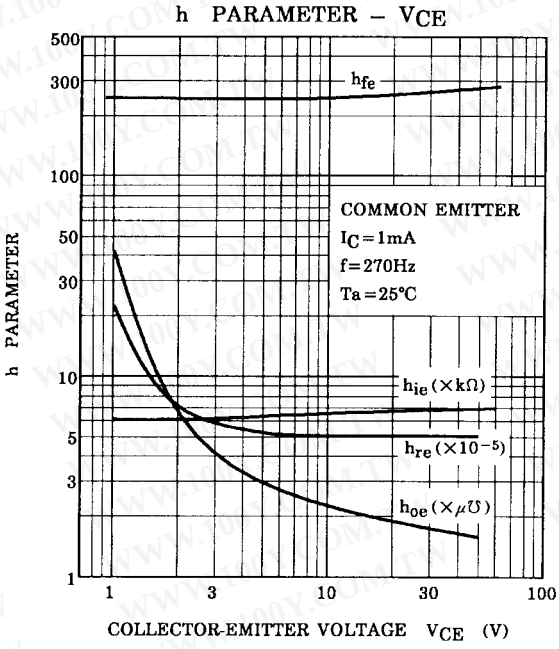
I_C – V_{BE}



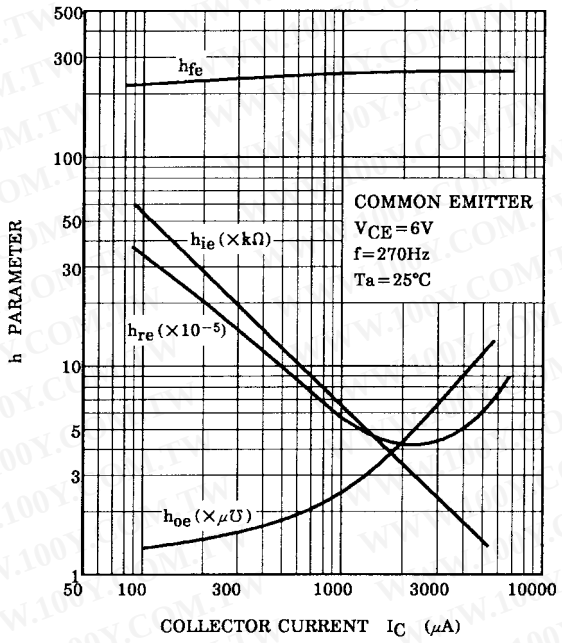
C_{ob} – V_{CB}



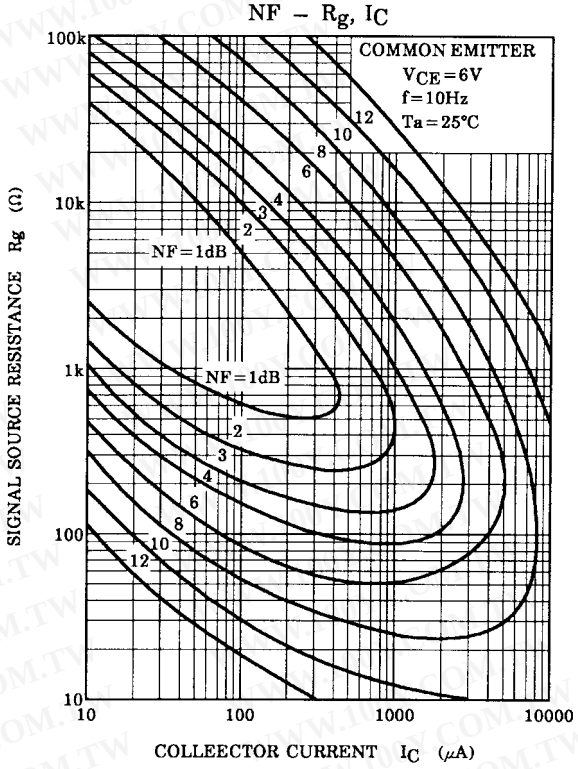
h PARAMETER – V_{CE}



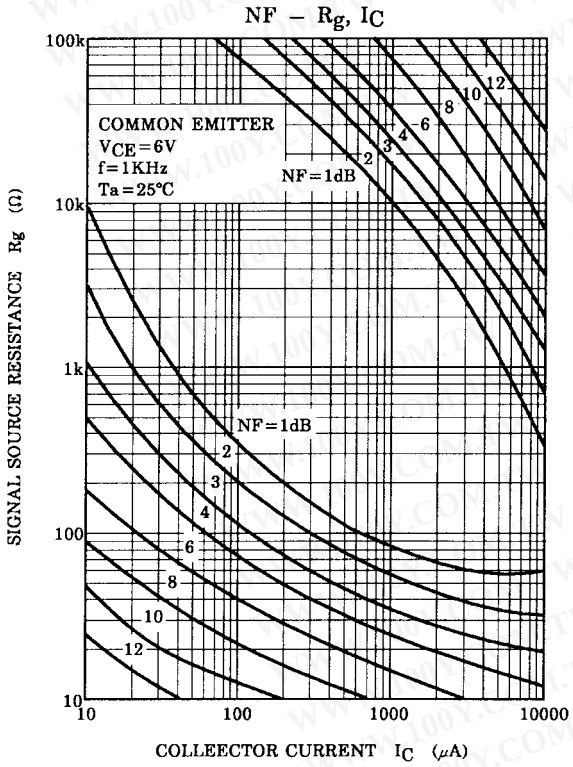
h PARAMETER – I_C



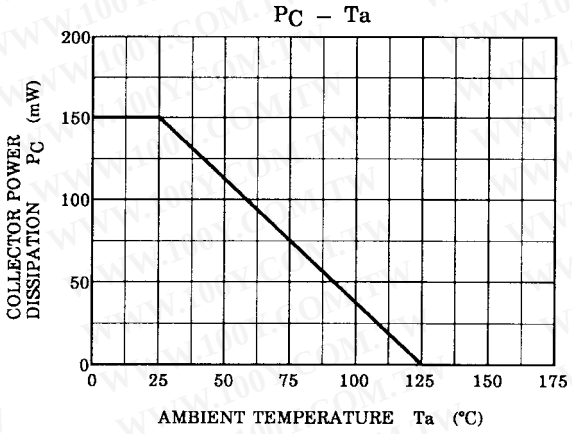
NF – R_g, I_C



NF – R_g, I_C



P_C – Ta



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